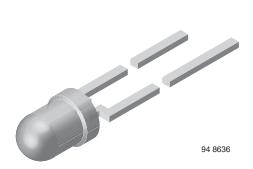
HALOGEN FREE

GREEN



## Vishay Semiconductors

# High Speed Infrared Emitting Diode, 940 nm, Surface Emitter Technology



### **DESCRIPTION**

As part of the SurfLight<sup>TM</sup> portfolio, the VSLY3943 is a high speed infrared emitting diode based on surface emitter technology, molded in a blue-gray plastic package.

### **FEATURES**

· Package type: leaded

• Package form: T-1, clear epoxy

• Dimensions: Ø 3 mm

• Peak wavelength:  $\lambda_p = 940 \text{ nm}$ 

· High speed

· High radiant power

• High radiant intensity

• Angle of half intensity:  $\phi = \pm 17^{\circ}$ 

· Low forward voltage

• Good spectral matching to Si photodetectors

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>



· Infrared remote control units

• Free air transmission systems

· Infrared source for optical counters and card readers

| PRODUCT SUMMARY |                        |         |                      |   |  |
|-----------------|------------------------|---------|----------------------|---|--|
| COMPONENT       | I <sub>e</sub> (mW/sr) | φ (deg) | $φ$ (deg) $λ_p$ (nm) |   |  |
| VSLY3943        | 70                     | ± 17    | 940                  | 5 |  |

#### Note

• Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION |           |                               |              |  |  |
|----------------------|-----------|-------------------------------|--------------|--|--|
| ORDERING CODE        | PACKAGING | REMARKS                       | PACKAGE FORM |  |  |
| VSLY3943             | Bulk      | MOQ: 5000 pcs, 5000 pcs/bulk  | T-1          |  |  |
| VSLY3943-MSZ         | Ammopack  | MOQ: 10 000 pcs, 2000 pcs/box | T-1          |  |  |

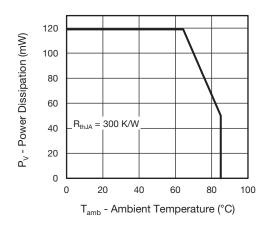
#### Note

· MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |             |      |
|--|--|-------------------|-------------|------|
| PARAMETER  | TEST CONDITION                         | SYMBOL            | VALUE       | UNIT |
| Reverse voltage  |  | V <sub>R</sub>    | 5           | V    |
| Forward current  |  | I <sub>F</sub>    | 70          | mA   |
| Peak forward current   | $t_p/T = 0.1$ , $t_p = 100 \mu s$      | I <sub>FM</sub>   | 140         | mA   |
| Surge forward current  | t <sub>p</sub> = 100 μs                | I <sub>FSM</sub>  | 500         | mA   |
| Power dissipation  |  | P <sub>V</sub>    | 160         | mW   |
| Junction temperature   |  | Tj                | 100         | °C   |
| Operating temperature range  |  | T <sub>amb</sub>  | -40 to +85  | °C   |
| Storage temperature range  |  | T <sub>stg</sub>  | -40 to +100 | °C   |
| Soldering temperature  | t ≤ 5 s, 2 mm from case                | T <sub>sd</sub>   | 260         | °C   |
| Thermal resistance junction-to-ambient   | J-STD-051, leads 7 mm, soldered on PCB | R <sub>thJA</sub> | 300         | K/W  |



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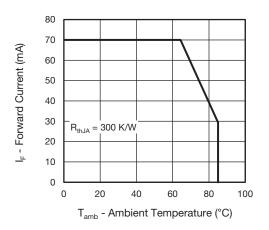


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                  |                                    |      |      |       |
|--|--|------------------|------------------------------------|------|------|-------|
| PARAMETER  | TEST CONDITION   | SYMBOL           | MIN.                               | TYP. | MAX. | UNIT  |
| Forward voltage  | $I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$                         | V <sub>F</sub>   | -                                  | 1.5  | 1.7  | V     |
|  | $I_F = 500 \text{ mA}, t_p = 100 \mu \text{s}$                     | V <sub>F</sub>   | -                                  | 2.6  | -    | V     |
| Temperature coefficient of V <sub>F</sub>                                    | I <sub>F</sub> = 50 mA   | TK <sub>VF</sub> | -                                  | -0.7 | -    | mV/K  |
| Reverse current  | V <sub>R</sub> = 5 V   | I <sub>R</sub>   | Not designed for reverse operation |      |      | μΑ    |
| Junction capacitance   | $V_R = 0 \text{ V, f} = 1 \text{ MHz,}$<br>$E = 0 \text{ mW/cm}^2$ | CJ               | -                                  | 30   | -    | pF    |
| Radiant intensity  | $I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$                         | l <sub>e</sub>   | 32                                 | 70   | 120  | mW/sr |
|  | $I_F = 500 \text{ mA}, t_p = 100 \mu \text{s}$                     | l <sub>e</sub>   | -                                  | 650  | -    | mW/sr |
| Radiant power  | $I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$                         | фе               | -                                  | 40   | -    | mW    |
| Temperature coefficient of radiant power                                     | I <sub>F</sub> = 50 mA   | TK <sub>φe</sub> | -                                  | -0.2 | -    | %/K   |
| Angle of half intensity  |  | φ                | -                                  | ± 17 | -    | deg   |
| Peak wavelength  | I <sub>F</sub> = 50 mA   | $\lambda_{p}$    | -                                  | 940  | -    | nm    |
| Spectral bandwidth   | I <sub>F</sub> = 70 mA   | Δλ               | -                                  | 55   | -    | nm    |
| Temperature coefficient of Ip  | I <sub>F</sub> = 70 mA   | $TK_{\lambdap}$  | -                                  | 0.28 | -    | nm    |
| Rise time  | I <sub>F</sub> = 70 mA, 10 % to 90 %                               | t <sub>r</sub>   | -                                  | 5    | -    | ns    |
| Fall time  | I <sub>F</sub> = 70 mA, 10 % to 90 %                               | t <sub>f</sub>   | -                                  | 6    | -    | ns    |

## Vishay Semiconductors

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

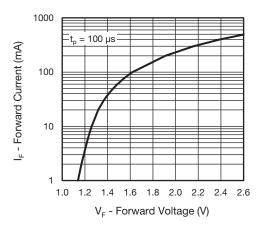


Fig. 3 - Forward Current vs. Forward Voltage

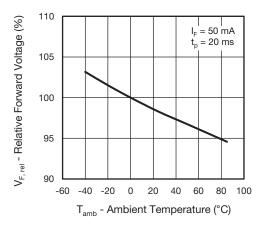


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

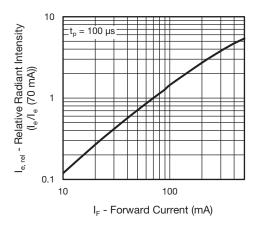


Fig. 5 - Relative Radiant Intensity vs. Forward Current

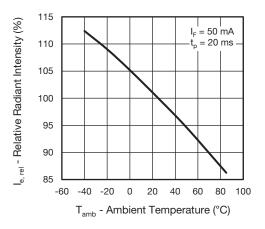


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

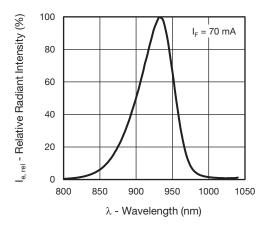


Fig. 7 - Relative Radiant Intensity vs. Wavelength

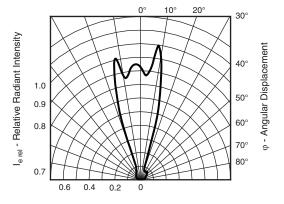
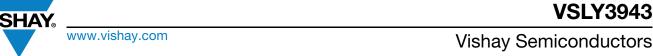
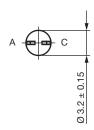
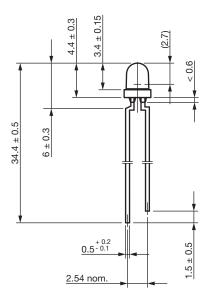


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement



### **PACKAGE DIMENSIONS** in millimeters





R1.4 (sphere) Area not plane  $\emptyset$  2.9  $\pm$  0.15

technical drawings according to DIN specifications

Drawing-No.: 6.541-5118.01-4

Issue: 1; 13.12.17



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